

Data Sheet January 2000 File Number 3962.2

6A, 1200V Ultrafast Diodes

The RURD6120 and RURD6120S are ultrafast diodes with soft recovery characteristics (t_{rr} < 70ns). They have low forward voltage drop and are silicon nitride passivated ionimplanted epitaxial planar construction.

These devices are intended for use as freewheeling/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

Formerly development type TA49039.

Ordering Information

PART NUMBER	PACKAGE	BRAND	
RURD6120	TO-251	UR6120	
RURD6120S	TO-252	UR6120	

NOTE: When ordering, use the entire part number. Add the suffix 9A to obtain the TO-252 variant in the tape and reel, i.e., RURD6120S9A.

Symbol



Features

	Ultrafast with Soft Recovery
•	Operating Temperature
•	Reverse Voltage

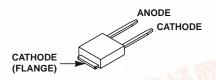
- Avalanche Energy Rated
- Planar Construction

Applications

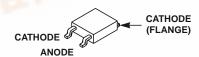
- · Switching Power Supplies
- Power Switching Circuits
- General Purpose

Packaging

JEDEC STYLE TO-251



JEDEC STYLE TO-252



Absolute Maximum Ratings T_C = 25°C, Unless Otherwise Specified

	RURD6120 RURD6120S	UNITS
Peak Repetitive Reverse VoltageVRRM	1200	V
Working Peak Reverse Voltage	1200	V
DC Blocking VoltageV _R	1200	V
Average Rectified Forward Current $I_{F(AV)}$ $(T_C = 140^{\circ}C)$	6	Α
(I _C = 140°C) Repetitive Peak Surge Current	12	Α
Non <mark>repetitive Peak Surge Current</mark>	60	Α
Maximum Power Dissipation	50	W
Avalanche Energy (See Figures 10 and 11)	10	mJ
Operating and Storage Temperature	-65 to 175	°C
(Leads at 0.063 in. (1.6mm) from case for 10s)	300	°C
Package Body for 10s, see Tech Brief 334T _{PKG}	260	°C

RURD6120, RURD6120S

 $\textbf{Electrical Specifications} \hspace{0.5cm} \textbf{T}_{C} = 25^{o}\text{C}, \hspace{0.1cm} \textbf{Unless Otherwise Specified}$

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V _F	I _F = 6A	-	-	2.1	V
	I _F = 6A, T _C = 150°C	-	-	1.9	V
I _R	V _R = 1200V	-	-	100	μА
	V _R = 1200V, T _C = 150 ^o C	-	-	500	μА
t _{rr}	I _F = 1A, dI _F /dt = 200A/μs	-	-	70	ns
	I _F = 6A, dI _F /dt = 200A/μs	-	-	90	ns
t _a	I _F = 6A, dI _F /dt = 200A/μs	-	45	-	ns
t _b	I _F = 6A, dI _F /dt = 200A/μs	-	30	-	ns
Q _{RR}	I _F = 6A, dI _F /dt = 200A/μs	-	400	-	nC
СЈ	V _R = 10V, I _F = 0A	-	22	-	pF
$R_{ heta JC}$		-	-	3	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

I_R = Instantaneous reverse current.

 t_{rr} = Reverse recovery time (See Figure 9), summation of t_a + t_b .

 t_a = Time to reach peak reverse current (See Figure 9).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

 Q_{RR} = Reverse recovery charge.

C_J = Junction Capacitance.

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

Typical Performance Curves

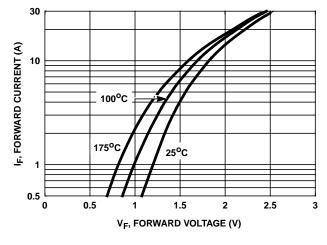


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

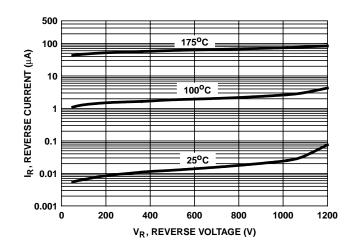


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

RURD6120, RURD6120S

Typical Performance Curves (Continued)

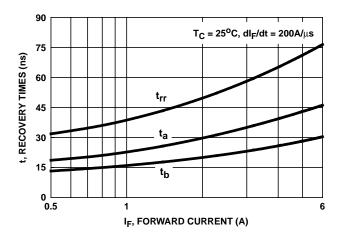


FIGURE 3. t_{rr} , t_a and t_b curves vs forward current

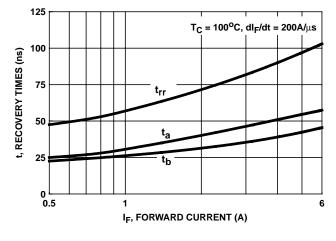


FIGURE 4. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

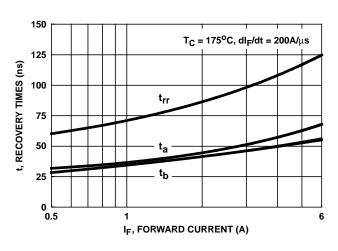


FIGURE 5. t_{rr} , t_a and t_b curves vs forward current

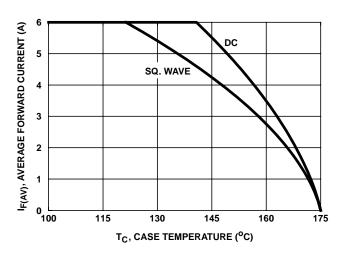


FIGURE 6. CURRENT DERATING CURVE

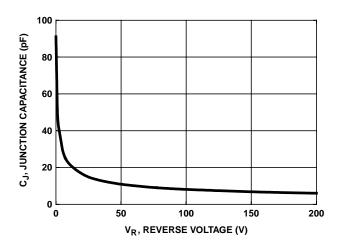


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

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RURD6120, RURD6120S

Test Circuits and Waveforms

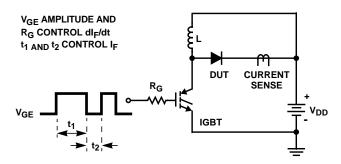


FIGURE 8. t_{rr} TEST CIRCUIT

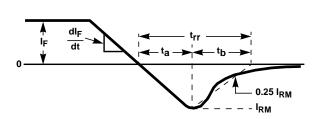


FIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

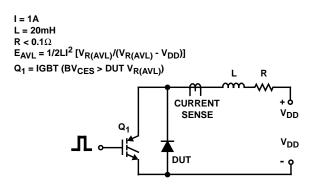


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

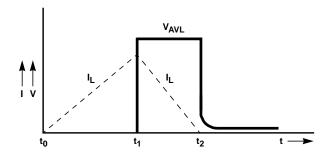


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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